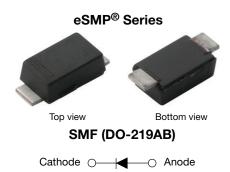
V2F22

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Surface-Mount TMBS® (Trench MOS Barrier Schottky) Rectifier



ADDITIONAL RESOURCES



| PRIMARY CHARACTERISTICS | | | |
|--|----------------|--|--|
| I _{F(AV)} | 2.0 A | | |
| V _{RRM} | 200 V | | |
| I _{FSM} | 60 A | | |
| V_F at I_F = 2 A (T_A = 125 °C) | 0.64 V | | |
| T _J max. | 175 °C | | |
| Package | SMF (DO-219AB) | | |
| Circuit configuration | Single | | |

FEATURES

- Trench MOS Schottky technology
- Low profile package
- Ideal for automated placement
- Low forward voltage drop, low power losses
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Wave and reflow solderable
- AEC-Q101 qualified available
 Automotive ordering code: base P/NHM3
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

TYPICAL APPLICATIONS

For use in high frequency inverters, freewheeling, DC/DC converters, and polarity protection in commercial, industrial, and automotive applications.

MECHANICAL DATA

Case: SMF (DO-219AB) Molding compound meets UL 94 V-0 flammability rating Base P/N-M3 - halogen-free, RoHS-compliant Base P/NHM3 - halogen-free, RoHS-compliant, and AEC-Q101 qualified

Terminals: matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

M3 and HM3 suffix meet JESD 201 class 2 whisker test

Polarity: color band denotes the cathode end

| MAXIMUM RATINGS ($T_A = 25$ °C unless otherwise noted) | | | | |
|--|---|-------------|------|--|
| PARAMETER | SYMBOL | V2F22 | UNIT | |
| Device marking code | | V2D | | |
| Maximum repetitive peak reverse voltage | V _{RRM} | 200 | V | |
| Maximum DC reverse voltage | V _{DC} | 160 | V | |
| Maximum average forward rectified current (fig.1) | I _{F(AV)} ⁽¹⁾ | 2.0 | A | |
| Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load | I _{FSM} | 60 | A | |
| Operating junction temperature range | T _J ⁽²⁾ -40 to +175 | | | |
| Storage temperature range | T _{STG} | -55 to +175 | | |

Notes

⁽¹⁾ Free air, mounted on recommended copper pad area

⁽²⁾ The heat generated must be less than the thermal conductivity from junction-to-ambient: $dP_D/dT_J < 1/R_{\theta JA}$

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| ELECTRICAL CHARACTERISTICS ($T_A = 25 \text{ °C}$ unless otherwise noted) | | | | | | |
|---|---|---------------------------|-------------------------------|------|------|------|
| PARAMETER | TEST CONDITIONS | | SYMBOL | TYP. | MAX. | UNIT |
| Instantaneous forward voltage | I _F = 1.0 A | T _A = 25 °C | | 0.72 | - | V |
| | I _F = 2.0 A | | V _F ⁽¹⁾ | 0.79 | 0.87 | |
| | I _F = 1.0 A | - T _A = 125 °C | VF | 0.56 | - | |
| | I _F = 2.0 A | | | 0.64 | 0.72 | |
| Reverse current | V - 160 V | T _A = 25 °C | | 0.3 | - | |
| | V _R = 160 V | T _A = 125 °C | I _R ⁽²⁾ | 300 | - | |
| | $V_{R} = 200 V$ $T_{A} = 25 °C$ $T_{A} = 125 °C$ | T _A = 25 °C | IR (=/ | - | 60 | μA |
| | | | 700 | 3500 |] | |
| Typical junction capacitance | 4.0 V, 1 MHz | | CJ | 160 | - | pF |

Notes

⁽¹⁾ Pulse test: 300 µs pulse width, 1 % duty cycle

⁽²⁾ Pulse test: Pulse width \leq 5 ms

| THERMAL CHARACTERISTICS ($T_A = 25$ °c unless otherwise noted) | | | |
|--|---------------------------------|-------|------|
| PARAMETER | SYMBOL | V2F22 | UNIT |
| Typical thermal resistance | R _{0JA} (1)(2) | 125 | °C/W |
| | R _{0JM} ⁽³⁾ | 26 | 0/00 |

Notes

 $^{(3)}$ The heat generated must be less than the thermal conductivity from junction-to-ambient: $dP_D/dT_J < 1/R_{\theta JA}$

 $^{(4)}$ Free air, mounted on recommended copper pad area; thermal resistance $R_{\theta JA}$ - junction to ambient

 $^{(5)}$ Mounted on recommended copper pad area; thermal resistance $R_{\theta JM}$ - junction to mount

| ORDERING INFORMATION (Example) | | | | | |
|--------------------------------|-----------------|------------------------|---------------|------------------------------------|--|
| PREFERRED P/N | UNIT WEIGHT (g) | PREFERRED PACKAGE CODE | BASE QUANTITY | DELIVERY MODE | |
| V2F22-M3/H | 0.015 | Н | 3000 | 7" diameter plastic tape and reel | |
| V2F22-M3/I | 0.015 | I | 10 000 | 13" diameter plastic tape and reel | |
| V2F22HM3/H ⁽¹⁾ | 0.015 | н | 3000 | 7" diameter plastic tape and reel | |
| V2F22HM3/I ⁽¹⁾ | 0.015 | l | 10 000 | 13" diameter plastic tape and reel | |

Note

(1) AEC-Q101 qualified



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RATINGS AND CHARACTERISTICS CURVES (T_A = 25 °C unless otherwise noted)

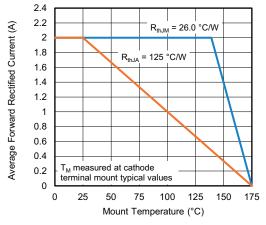


Fig. 1 - Maximum Forward Current Derating Curve

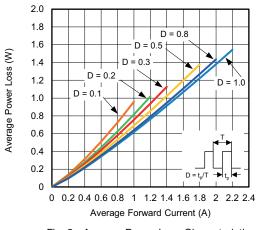


Fig. 2 - Average Power Loss Characteristics

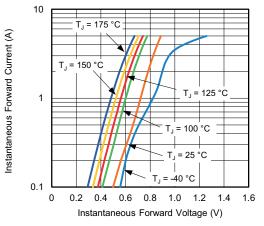


Fig. 3 - Typical Instantaneous Forward Characteristics

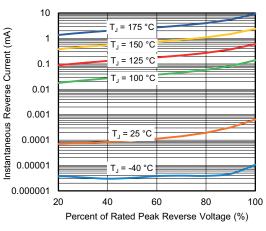
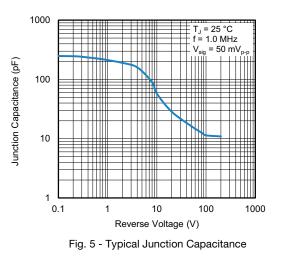


Fig. 4 - Typical Reverse Leakage Characteristics



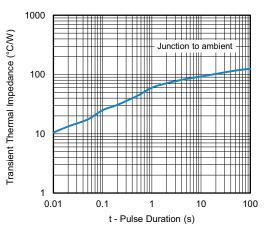


Fig. 6 - Typical Transient Thermal Impedance

Revision: 04-Dec-2019

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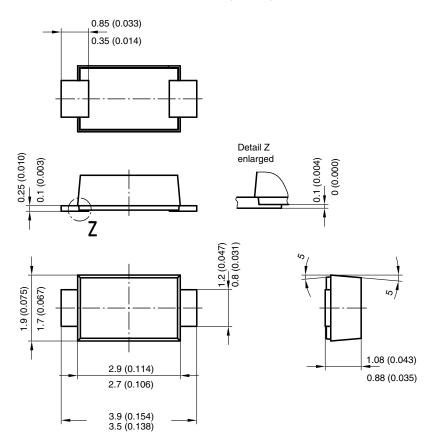
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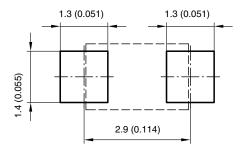
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PACKAGE OUTLINE DIMENSIONS in millimeters (inches)



Foot print recommendation:



Created - Date: 15. February 2005 Rev. 3 - Date: 13. March 2007 Document no.:S8-V-3915.01-001 (4) 17247

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